

## KSC3552

# High Voltage and High Reliabilty • High Speed Switching

- Wide SOA



### **NPN Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

| Symbol           | Parameter                                    | Value      | Units |
|------------------|--|------------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage                       | 1100       | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage                    | 800        | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage                         | 7          | V     |
| I <sub>C</sub>   | Collector Current (DC)                       | 12         | Α     |
| I <sub>CP</sub>  | Collector Current (Pulse)                    | 30         | Α     |
| I <sub>B</sub>   | Base Current                                 | 6          | Α     |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> =25°C) | 150        | W     |
| T <sub>J</sub>   | Junction Temperature                         | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                          | - 55 ~ 150 | °C    |

### **Electrical Characteristics** $T_C=25$ °C unless otherwise noted

| Symbol                 | Parameter                            | Test Condition   | Min. | Тур. | Max. | Units |
|------------------------|--------------------------------------|--|------|------|------|-------|
| BV <sub>CBO</sub>      | Collector-Base Breakdown Voltage     | $I_C = 1 \text{mA}, I_E = 0$                                       | 1100 |      |      | V     |
| BV <sub>CEO</sub>      | Collector-Emitter Breakdown Voltage  | $I_{C} = 5mA, I_{B} = 0$   | 800  |      |      | V     |
| BV <sub>EBO</sub>      | Emitter-Base Breakdown Voltage       | $I_E = 1 \text{mA}, I_C = 0$                                       | 7    |      |      | V     |
| V <sub>CEX</sub> (sus) | Collector-Emitter Sustaining Voltage | $I_C = 6A$ , $I_{B1} = -I_{B2} = 1.2A$<br>L = 500 $\mu$ H, Clamped | 800  |      |      | V     |
| I <sub>CBO</sub>       | Collector Cut-off Current            | $V_{CB} = 800V, I_{E} = 0$   |      |      | 10   | μΑ    |
| I <sub>EBO</sub>       | Emitter Cut-off Current              | $V_{EB} = 5V, I_{C} = 0$   |      |      | 10   | μΑ    |
| h <sub>FE1</sub>       | DC Current Gain                      | $V_{CE} = 5V, I_{C} = 0.8A$  | 10   |      | 40   |       |
| h <sub>FE2</sub>       |                                      | $V_{CE} = 5V$ , $I_C = 4A$   | 8    |      |      |       |
| V <sub>CE</sub> (sat)  | Collector-Emitter Saturation Voltage | $I_C = 6A, I_B = 1.2A$   |      |      | 2    | V     |
| V <sub>BE</sub> (sat)  | Base-Emitter Saturation Voltage      | $I_C = 6A, I_B = 1.2A$   |      |      | 1.5  | V     |
| C <sub>ob</sub>        | Output Capacitance                   | V <sub>CB</sub> = 10V, f = 1MHz                                    |      | 215  |      | pF    |
| f <sub>T</sub>         | Current Gain Bandwidth Product       | $V_{CE} = 10V, I_{C} = 0.8A$                                       |      | 15   |      | MHz   |
| t <sub>ON</sub>        | Turn ON Time                         | V <sub>CC</sub> = 400V   |      |      | 0.5  | μs    |
| t <sub>STG</sub>       | Storage Time                         | $51_{B1} = -2.5I_{B2} = I_{C} = 8A$                                |      |      | 3    | μs    |
| t <sub>F</sub>         | Fall Time                            | $R_L = 50\Omega$   |      |      | 0.3  | μs    |

## $h_{\text{FE}}$ Classification

| Classification  | N       | R       | 0       |
|-----------------|---------|---------|---------|
| h <sub>FE</sub> | 10 ~ 20 | 15 ~ 30 | 20 ~ 40 |

# **Typical Characteristics**

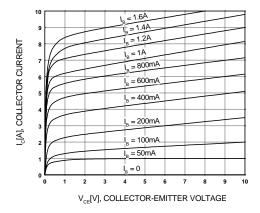


Figure 1. Static Characteristic

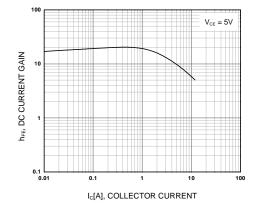


Figure 2. DC current Gain

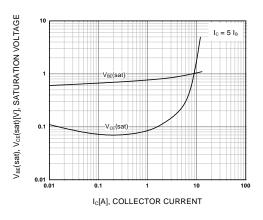


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

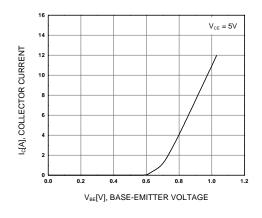


Figure 4. Base-Emitter on Voltage

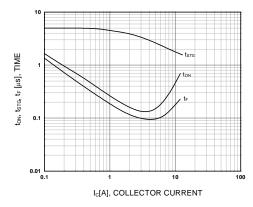


Figure 5. Turn On Time

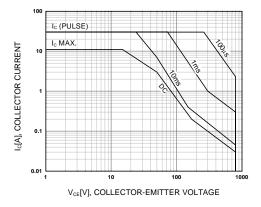


Figure 6. Safe Operating Area

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# Typical Characteristics (Continued)

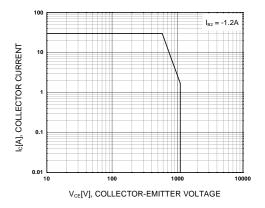


Figure 7. Reverse Bias Safe Operating Area

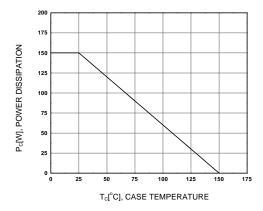
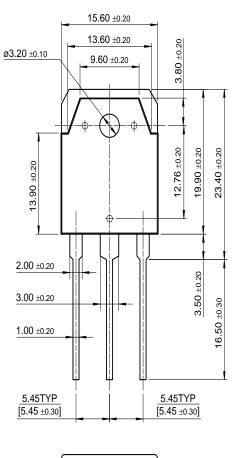
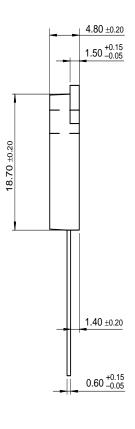


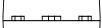
Figure 8. Power Derating

# **Package Demensions**

# TO-3P







Dimensions in Millimeters

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| DenseTrench™         | GTO™                | PowerTrench <sup>®</sup> | SuperSOT™-8           |
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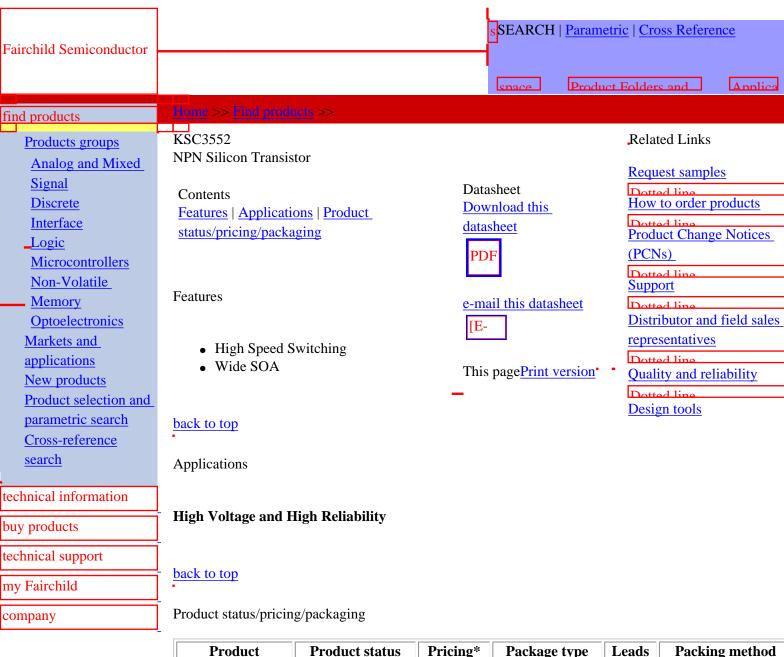
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| Product    | Product status  | Pricing* | Package type | Leads | Packing method |
|------------|-----------------|----------|--------------|-------|----------------|
| KSC3552RTU | Full Production | \$2.20   | TO-3P        | 3     | RAIL           |
| KSC3552OTU | Full Production | \$2.20   | TO-3P        | 3     | RAIL           |
| KSC3552NTU | Full Production | \$2.20   | TO-3P        | 3     | RAIL           |

<sup>\* 1,000</sup> piece Budgetary Pricing

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